

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62308AP, TD62308F, TD62308AF

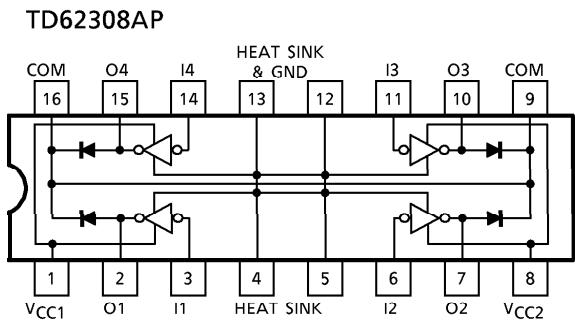
4CH LOW INPUT ACTIVE HIGH-CURRENT DARLINGTON SINK DRIVER

The TD62308AP / F / AF are non-inverting transistor array which are comprised of four NPN darlington output stages and PNP input stages.

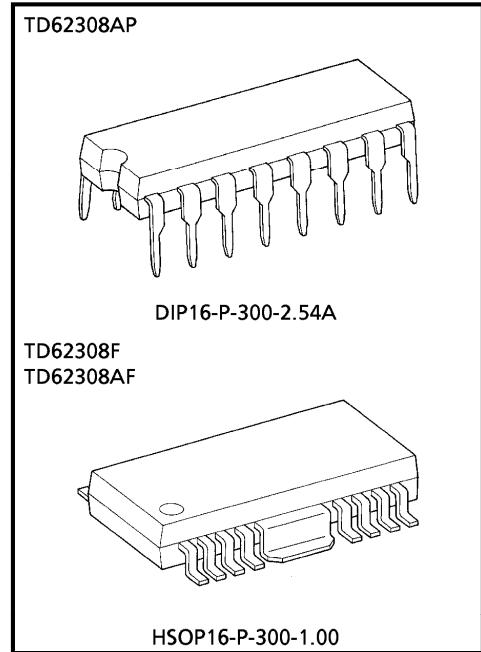
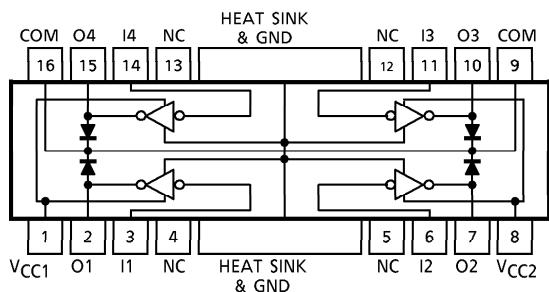
These devices are low level input active driver and are suitable for operation with TTL, 5V CMOS and 5V Microprocessor which have sink current output drivers. Applications include relay, hammer, lamp and stepping motor drivers.

FEATURES

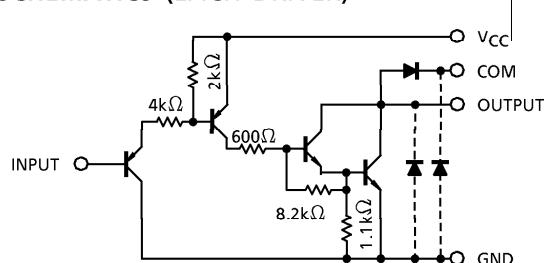
- Output current (single output) 1.5A (Max.)
- High sustaining voltage output 35V (Min.) (TD62308F)
50V (Min.) (TD62308AP, TD62308AF)
- Output clamp diodes
- Input compatible with TTL and 5V CMOS
- Low level active inputs
- Standard supply voltage
- Two V_{CC} terminals V_{CC1} , V_{CC2} (separated)
- GND and SUB terminal = heat sink
- Package type-AP : DIP-16pin
- Package type-F, AF : PFP-16pin

PIN CONNECTION (TOP VIEW)

TD62308F, TD62308AF



Weight
DIP16-P-300-2.54A : 1.11g (Typ.)
HSOP16-P-300-1.00 : 0.50g (Typ.)

SCHEMATICS (EACH DRIVER)

(Note) The input and output parasitic diodes cannot be used as clamp diodes.

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		V _{CC}	-0.5~10	V
Output Sustaining Voltage	F	V _{CE} (SUS)	-0.5~35	V
	AP, AF		-0.5~50	
Output Current		I _{OUT}	1.5	A / ch
Input Current		I _{IN}	-10	mA
Input Voltage		V _{IN}	-0.5~30	V
Clamp Diode Reverse Voltage	F	V _R	35	V
	AP, AF		50	
Clamp Diode Forward Current		I _F	1.5	A
Power Dissipation	AP	P _D	1.47 / 2.7 (Note 1)	W
	F, AF		0.9 / 1.4 (Note 2)	
Operating Temperature		T _{opr}	-40~85	°C
Storage Temperature		T _{stg}	-55~150	°C

(Note 1) On Glass Epoxy (50×50×1.6mm Cu 50%)

(Note 2) On Glass Epoxy (60×30×1.6mm Cu 30%)

RECOMMENDED OPERATING CONDITIONS (Ta = -40~85°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage		V _{CC}	—	4.5	—	5.5	V
Output Sustaining Voltage	F	V _{CE} (SUS)	—	0	—	35	V
	AP, AF		—	0	—	50	
Output Current	AP	I _{OUT}	DC 1 circuit, Ta = 25°C	0	—	1250	mA / ch
			T _{pw} = 25ms	0	—	1250	
			Duty = 10%	0	—	1250	
			4 circuits	0	—	700	
			Ta = 85°C	0	—	1250	
	F, AF		Duty = 10%	0	—	1250	
Input Voltage		V _{IN}	—	0	—	25	V
Input Voltage	Output On	V _{IN} (ON)	—	0	—	V _{CC} - 3.6	V
	Output Off	V _{IN} (OFF)	—	V _{CC} - 1.0	—	V _{CC}	
Clamp Diode Reverse Voltage	F	V _R	—	—	—	35	V
	AP, AF		—	—	—	50	
Clamp Diode Forward Current		I _F	—	—	—	1.25	A
Power Dissipation	AP	P _D	Ta = 85°C (Note 1)	—	—	1.4	W
	F, AF		Ta = 85°C (Note 2)	—	—	0.7	

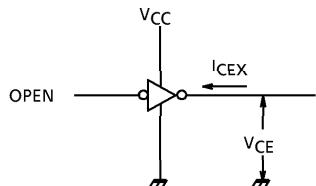
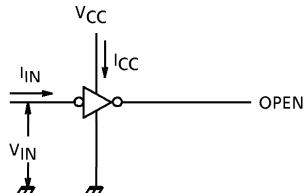
(Note 1) On Glass Epoxy (50×50×1.6mm Cu 50%)

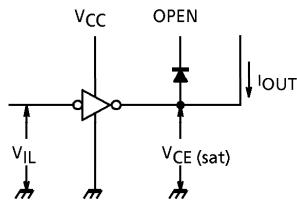
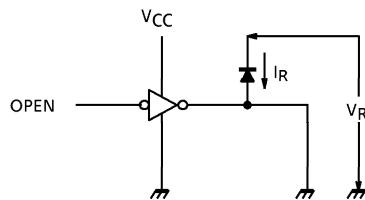
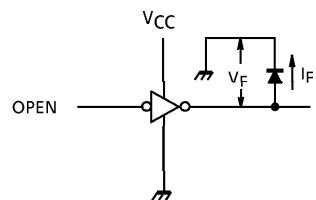
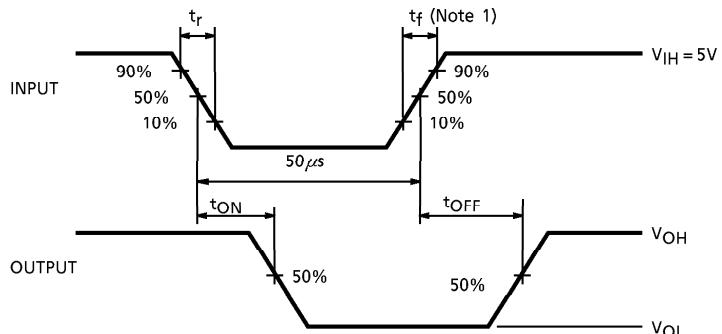
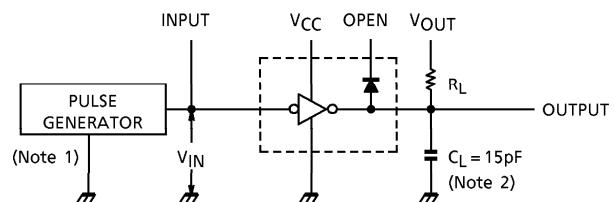
(Note 2) On Glass Epoxy (60×30×1.6mm Cu 30%)

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT		
Output Leakage Current	AP, AF	I_{CEX}	1	$V_{CE} = 50\text{V}, T_a = 25^\circ\text{C}$	—	—	50	μA			
	F			$V_{CE} = 50\text{V}, T_a = 85^\circ\text{C}$	—	—	100				
				$V_{CE} = 35\text{V}, T_a = 25^\circ\text{C}$	—	—	50				
				$V_{CE} = 35\text{V}, T_a = 85^\circ\text{C}$	—	—	100				
Output Saturation Voltage		V_{CE} (sat)	3	$I_{OUT} = 1.25\text{A}$	—	—	1.8	V			
				$I_{OUT} = 0.7\text{A}$	—	—	1.3				
Input Voltage	"H" Level	V_{IH}	—	—	$V_{CC} - 1.6$	—	25	V			
	"L" Level	V_{IL}	—	—	—	—	$V_{CC} - 3.6$				
Input Current	"H" Level	I_{IH}	—	—	—	—	10	μA			
	"L" Level	I_{IL}		—	—	—	-0.05	-0.36 mA			
Clamp Diode Reverse Current	AP, AF	I_R	4	$V_R = 50\text{V}, T_a = 25^\circ\text{C}$	—	—	50	μA			
	F			$V_R = 35\text{V}, T_a = 25^\circ\text{C}$	—	—	50				
Clamp Diode Forward Voltage		V_F	5	$I_F = 1.25\text{A}$	—	1.5	2.0	V			
Supply Current	Output On	I_{CC} (ON)	2	$V_{CC} = 5.5\text{V}, V_{IN} = 0\text{V}$	—	8.5	12.5	mA / ch			
	Output Off	I_{CC} (OFF)		$V_{CC} = 5.5\text{V}, V_{IN} = V_{CC}$	—	—	1.0				
Turn-On Delay	F	t_{ON}	6	$C_L = 15\text{pF}$	$V_{OUT} = 35\text{V}$ $R_L = 28\Omega$	—	0.2	—	μs		
	AP, AF				$V_{OUT} = 50\text{V}$ $R_L = 40\Omega$	—	—	—			
Turn-Off Delay	F	t_{OFF}			$V_{OUT} = 35\text{V}$ $R_L = 28\Omega$	—	5.0	—			
	AP, AF				$V_{OUT} = 35\text{V}$ $R_L = 40\Omega$	—	—	—			

TEST CIRCUIT

1. I_{CEX} 2. I_{CC} 

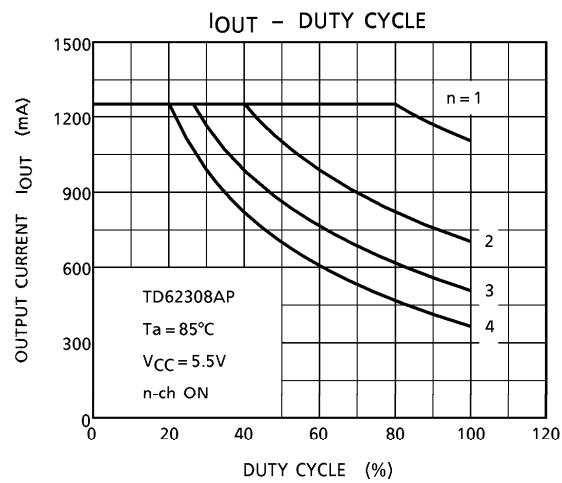
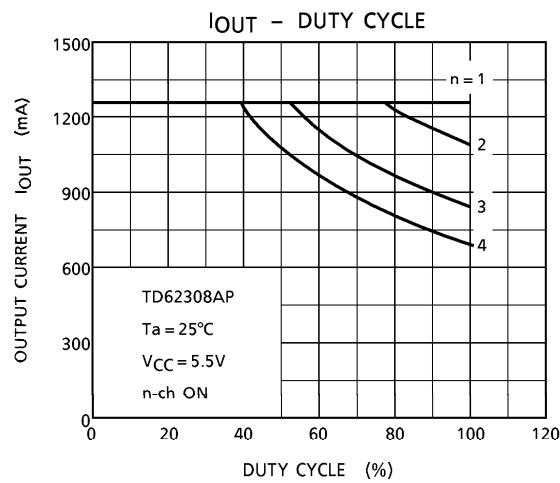
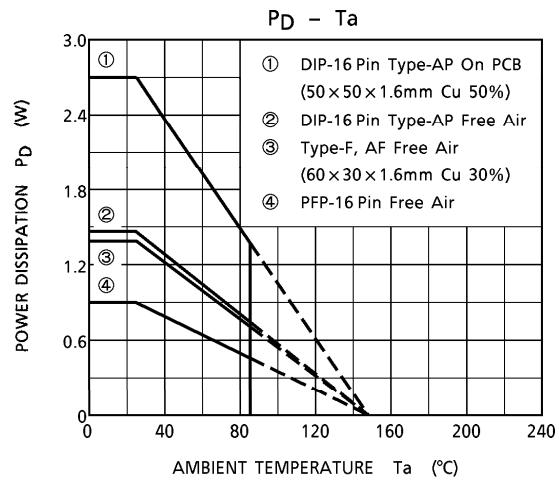
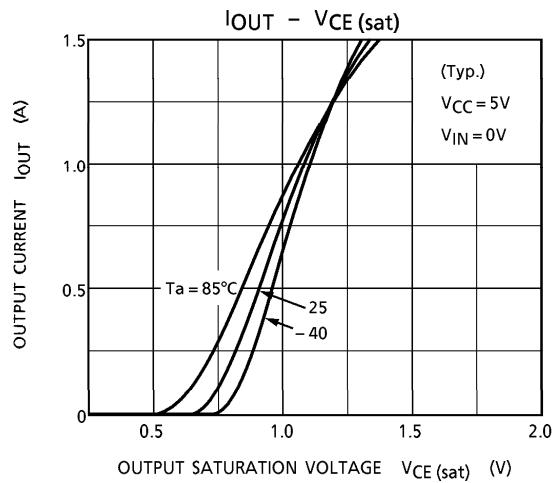
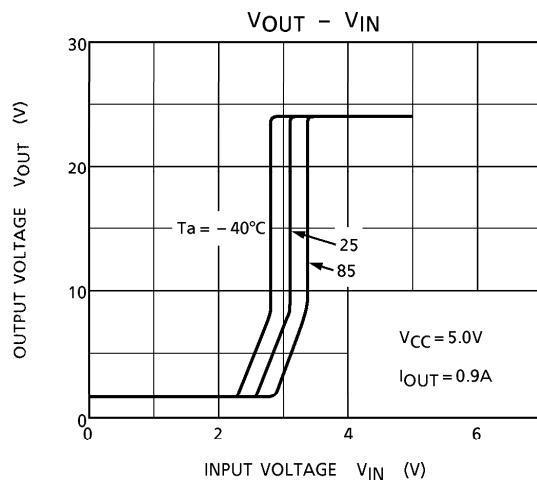
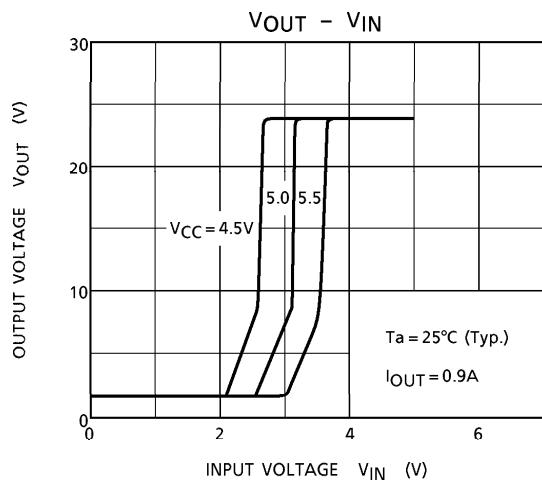
3. $V_{CE(\text{sat})}$ 4. I_R 5. V_F 6. t_{ON}, t_{OFF} 

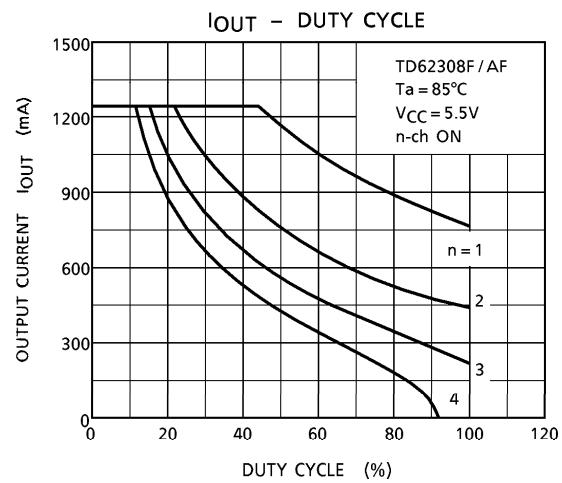
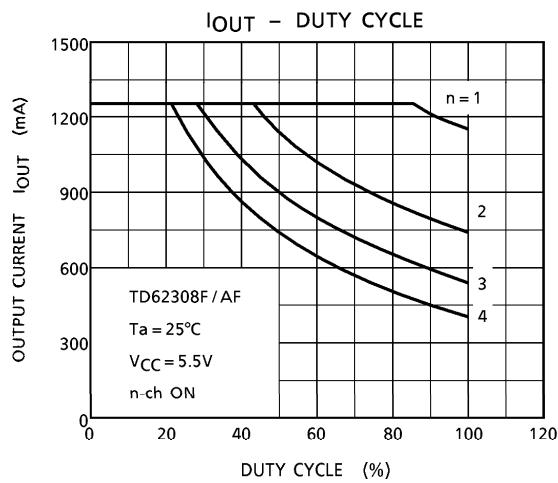
(Note 1) Pulse width $50\mu\text{s}$, duty cycle 10%
Output impedance 50Ω $t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$

(Note 2) C_L includes probe and jig capacitance.

PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, V_{CC} , COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

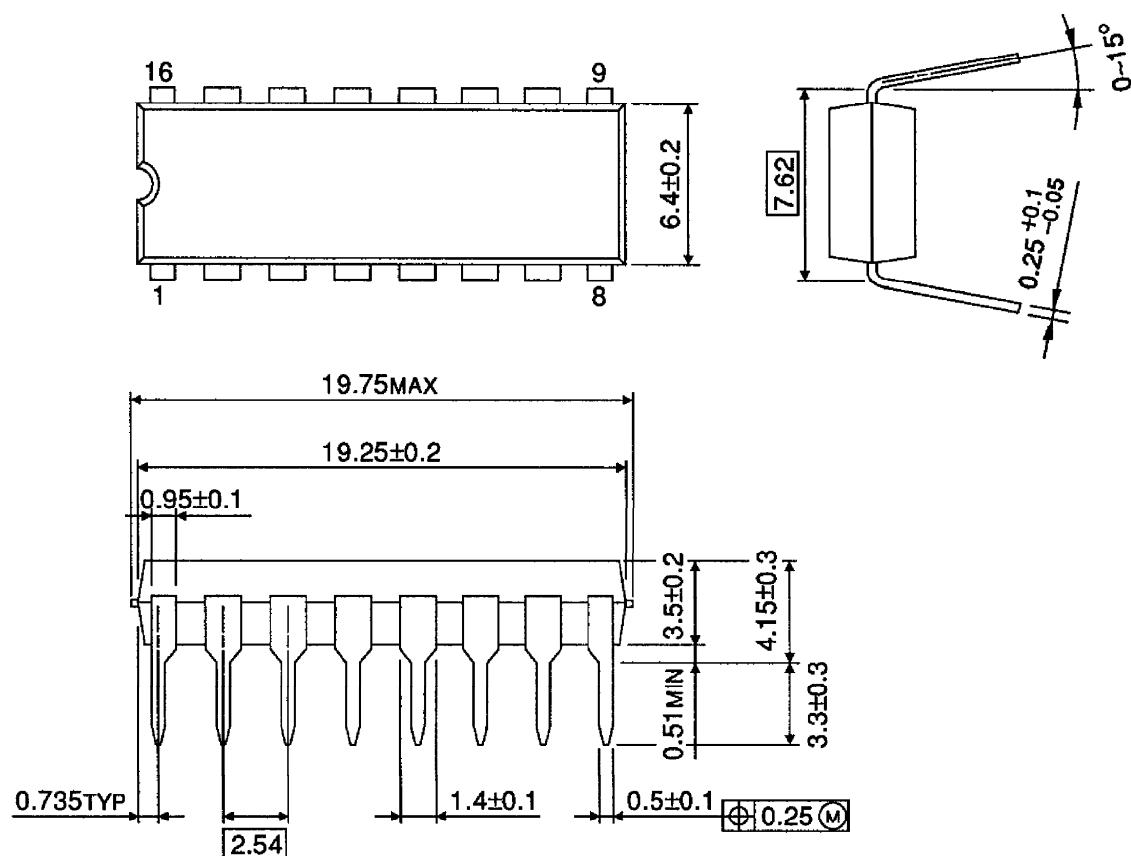




OUTLINE DRAWING

DIP16-P-300-2.54A

Unit : mm

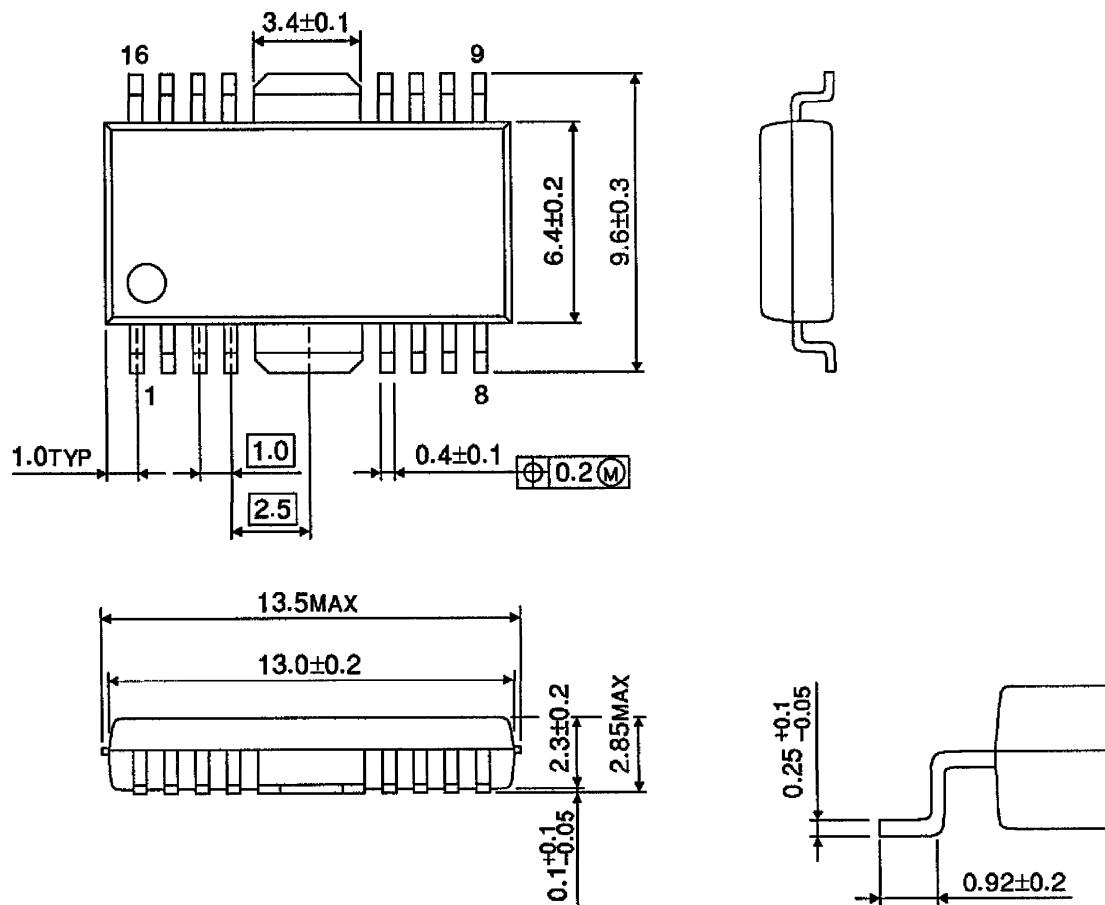


Weight : 1.11g (Typ.)

OUTLINE DRAWING

HSOP16-P-300-1.00

Unit : mm



Weight : 0.50g (Typ.)